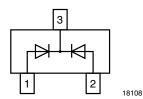


Vishay Semiconductors

Dual Varicap Diode





MECHANICAL DATA

Case: SOT-23
Weight: approx. 8.1 mg
Packaging codes/options:

08/3 k per 7" reel (8 mm tape), 15 k/box

FEATURES

- Silicon epitaxial planar diode
- · Common cathode
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Find out more about Vishay's Automotive Grade Product requirements at: www.vishay.com/applications

AUTOMOTIVE GRADE







APPLICATIONS

- Tuning of separate resonant circuits
- Push-pull circuits in FM range
- Especially for car radios

PARTS TABLE						
PART	TYPE DIFFERENTIATION	ORDERING CODE	TYPE MARKING	REMARKS		
BB814-1-V-GH	$V_{RRM} = 20 \text{ V}, C_{D2} = 43 \text{ pF to } 45.5 \text{ pF}$	BB814-1-V-GH-08	SG1	Tape and reel		
BB814-2-V-GH	$V_{RRM} = 20 \text{ V}, C_{D2} = 44.5 \text{ pF to } 46.5 \text{ pF}$	BB814-2-V-GH-08	SG2	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		V_{RRM}	20	V	
Reverse voltage		V_{R}	18	V	
Forward current		I _F	50	mA	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Junction temperature		Tj	125	°C	
Storage temperature range		T _{stg}	- 55 to + 150	°C	

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse current	V _R = 16 V		I _R			20	nA
	$V_R = 16 \text{ V}, T_j = 60 ^{\circ}\text{C}$		I _R			200	nA
	V _R = 2 V	BB814-1-V-GH	C _{D2}	43		45.5	pF
Diode capacitance (1)		BB814-2-V-GH	C _{D2}	44.5		46.5	pF
blode capacitance w	V _R = 8 V	BB814-1-V-GH	C _{D8}	19.1		21.95	pF
		BB814-2-V-GH	C _{D8}	19.75		22.70	pF
Capacitance ratio	V _R = 2 V, 8 V, f = 1 MHz		C _{D2} /C _{D8}	2.05		2.25	
Series resistance	$C_D = 38 \text{ pF, f} = 100 \text{ MHz}$		Rs			0.5	Ω

Note

 $^{(1)}$ In the reverse voltage range of V_R = (2 V to 8 V) for diodes 4 taped in sequence the max. deviation is 3 %

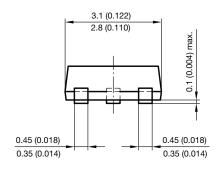
^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

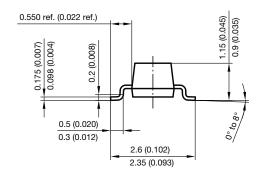
Vishay Semiconductors

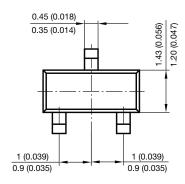
Dual Varicap Diode

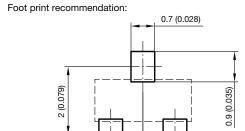


PACKAGE DIMENSIONS in millimeters (inches): SOT-23









0.95 (0.037)

0.95 (0.037)

Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009

17418



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 Revision: 18-Jul-08

www.vishay.com